

PATENT ASSIGNMENT

Electronic Version v1.1

Stylesheet Version v1.1

SUBMISSION TYPE:

NEW ASSIGNMENT

NATURE OF CONVEYANCE:

ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
Spancion Inc.	01/31/2007

RECEIVING PARTY DATA

Name:	Spancion LLC
Street Address:	915 DeGuigne Drive, P.O. Box 3453
Internal Address:	Mail Stop 250
City:	Sunnyvale
State/Country:	CALIFORNIA
Postal Code:	94088-3453

PROPERTY NUMBERS Total: 35

Property Type	Number
Patent Number:	6433383
Patent Number:	6232630
Patent Number:	6133619
Patent Number:	6124640
Patent Number:	6211074
Patent Number:	6436850
Patent Number:	6060741
Patent Number:	6011289
Patent Number:	6080639
Patent Number:	5973353
Patent Number:	6159860
Patent Number:	5977601
Patent Number:	6383939
Patent Number:	6372651

PATENT

500246933

REEL: 019069 FRAME: 0040

CH \$1400.00 6433383

Patent Number:	6515328
Patent Number:	6159794
Patent Number:	6074956
Patent Number:	6110779
Patent Number:	6452225
Patent Number:	5948703
Patent Number:	6534411
Patent Number:	6072191
Patent Number:	6350627
Patent Number:	5972749
Patent Number:	6066873
Patent Number:	5994780
Patent Number:	6211058
Patent Number:	6316293
Patent Number:	6667511
Patent Number:	6017786
Patent Number:	6166439
Patent Number:	6235586
Patent Number:	6001688
Patent Number:	6046085
Patent Number:	5933729

CORRESPONDENCE DATA

Fax Number: (408)616-3762

Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Phone: 408-616-3722

Email: sally.nieto@spansion.com

Correspondent Name: Raymond E. Fritz

Address Line 1: 915 DeGuigne Drive, P.O. Box 3453

Address Line 2: Mail Stop 250

Address Line 4: Sunnyvale, CALIFORNIA 94088-3453

NAME OF SUBMITTER:

Raymond E. Fritz

Total Attachments: 4

source=Spansion Inc to LLC P8#page1.tif

source=Spansion Inc to LLC P8#page2.tif

source=Spansion Inc to LLC P8#page3.tif

source=Spansion Inc to LLC P8#page4.tif

ASSIGNMENT AGREEMENT

This Assignment Agreement by and between **SPANSION INC.**, a corporation of Delaware having a place of business at 915 DeGuigne Drive, P. O. Box 3453, Sunnyvale, California 94088-3453, U.S.A., its affiliates and subsidiaries, (hereinafter referred to as "ASSIGNOR") and **SPANSION LLC**, a limited liability company of Delaware, having a place of business at 915 DeGuigne Drive, P. O. Box 3453, Sunnyvale, California, 94088-3453, U.S.A. (hereinafter "ASSIGNEE") is effective on the 21st day of December, 2005.

In consideration of good and valuable consideration, the receipt of which is hereby acknowledged, ASSIGNOR hereby assigns, transfers and conveys all of their right, title and interest in the United States and throughout the world in and to all invention disclosures, United States patent applications, United States patents, foreign patents, and foreign patent applications (including any Patent Cooperation Treaty (PCT) applications) identified on Schedule A attached hereto and made a part hereof, and the entire right, title and interest in the United States and throughout the world in and to the inventions to which said invention disclosures, patents and patent applications pertain, in and to all worldwide rights of priority, and in and to any corresponding United States and foreign patents, extensions and renewals of patents, results of reexamination, substitutions, reissues, patent applications, divisionals, continuations, continuations-in-part, utility models, petty patents, patents of importation, invention registrations, and inventor's certificates, together with all the rights and privileges granted and secured by said patents, extensions and renewals of patents, results of reexamination, substitutions, reissues, patent applications, divisionals, continuations, continuations-in-part, utility models, petty patents, patents of importation, invention registrations and inventor's certificates, including without limitation all claims, demands, rights and causes of action that ASSIGNOR may have against others on account of any past, present and future infringement of any of said patents, patent applications, utility models, petty patents, patents of importation, invention registrations, and inventor's certificates with the right in ASSIGNEE to sue for and obtain all relief to which ASSIGNOR may have been entitled by reason of any such infringement. ASSIGNOR further agrees that ASSIGNEE may apply for and receive Letters Patent, utility models, petty patents, patents of importation, invention registrations, and inventor's certificates for said inventions in its own name.

Said entire right, title, and interest is to be held and enjoyed by ASSIGNEE for its own use and benefit and for the use and benefit of its successors and assigns, to the full end of the term for which said patents, registrations or certificates may be granted, as fully and entirely as the same would have been held and enjoyed by ASSIGNOR had this assignment and sale not been made.

ASSIGNOR's assignment, transference and conveyance of all of its right, title and interest in the United States and throughout the world hereunder is made subject to any rights, licenses or immunities relating to such rights, titles and interests that have been granted to any persons by ASSIGNOR or its assignors.

IN WITNESS WHEREOF, the ASSIGNOR and ASSIGNEE have caused this Assignment Agreement to be executed by their respective duly authorized representatives as of December 21, 2005.

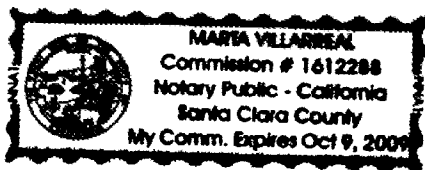
**ASSIGNOR
SPANSION INC.**

By: [Signature]
Name: Robert C. Melendres
Title: Executive Vice President, Corporate Development,
General Counsel and Corporate Secretary

Date: January 31, 2007

State of **CALIFORNIA**)
County of **SANTA CLARA**)

On January 31, 2007, before me, Marta Villarreal, a Notary Public, personally appeared Robert C. Melendres, personally known to me or proved to me on the basis of satisfactory evidence to be the person whose name is subscribed to the within instrument and acknowledged to me that he/she executed the same in his/her authorized capacity, and that by his/her signature on the instrument the person, or the entity upon behalf of which the person acted, executed the instrument.



Witness my hand and official seal.

[Signature]
SIGNATURE OF NOTARY

**ASSIGNEE
SPANSION LLC**

By: [Signature]
Name: Robert C. Melendres
Title: Executive Vice President, Corporate Development,
General Counsel and Corporate Secretary

Date: January 31, 2007

State of CALIFORNIA)
County of SANTA CLARA)

On January 31, 2007, before me, Marta Villarreal, a Notary Public, personally appeared Rodriguez C. Melendez, personally known to me or proved to me on the basis of satisfactory evidence to be the person whose name is subscribed to the within instrument and acknowledged to me that he/she executed the same in his/her authorized capacity, and that by his/her signature on the instrument the person, or the entity upon behalf of which the person acted, executed the instrument.

Witness my hand and official seal.



Marta Villarreal
SIGNATURE OF NOTARY

Docket No.	Country	Status	Application	File Date	Grant Date	Owner	Patent No.	Title
C646497	USA	Granted	09/357,333	7/20/1999	8/13/2002	A2S	6,433,383	METHODS AND ARRANGEMENTS FOR FORMING A
C650497	USA	Granted	09/348,583	7/7/1999	5/15/2001	A2S	6,232,630	LIGHT FLOATING GATE DOPING TO IMPORVE
C651497	USA	Granted	09/144,521	8/31/1998	10/17/2000	A2S	6,133,619	REDUCTION OF SILICON OXYNITRIDE FILM
C652497	USA	Granted	09/144,506	8/31/1998	9/26/2000	A2S	6,124,640	SCALABLE AND RELIABLE INTEGRATED CIRCUIT
C654497	USA	Granted	09/076,584	5/12/1998	4/3/2001	A2S	6,211,074	METHODS AND ARRANGEMENTS FOR REDUCING
C658497	USA	Granted	09/652,132	8/31/2000	8/20/2002	A2S	6,436,850	METHOD OF DEGASSING LOW K DIELECTRIC FOR
C660497	USA	Granted	09/154,072	9/16/1998	5/9/2000	A2S	6,060,741	STACKED GATE STRUCTURE FOR FLASH MEMORY
C661497	USA	Granted	09/154,073	9/16/1998	1/4/2000	A2S	6,011,289	METAL OXIDE STACK FOR FLASH MEMORY
C663497	USA	Granted	09/199,265	11/25/1998	6/27/2000	A2S	6,080,639	SEMICONDUCTOR DEVICE CONTAINING P-HDP
C665497	USA	Granted	08/992,951	5/10/1999	10/26/1999	A2S	5,973,353	METHODS AND ARRANGEMENTS FOR FORMING A
C666497	USA	Granted	09/118,375	6/14/1999	12/12/2000	A2S	6,159,860	METHOD FOR ETCHING LAYERS ON A
C667497	USA	Granted	09/118,377	7/17/1998	11/2/1999	A2S	5,977,601	METHOD FOR ETCHING MEMORY GATE STACK
C667497	USA	Granted	09/375,504	8/17/1999	5/7/2002	A2S	6,383,939	METHOD FOR ETCHING MEMORY GATE STACK
C668497	USA	Granted	09/286,464	4/6/1999	4/16/2002	A2S	6,372,651	METHOD FOR TRIMMING A PHOTORESIST PATTERN
C672497	USA	Granted	09/244,429	2/4/1999	2/4/2003	A2S	6,515,328	METHOD FOR ETCHING SILICON LAYERS ON A
C673497	USA	Granted	09/076,662	5/12/1998	12/12/2000	A2S	6,159,794	METHODS FOR REMOVING SILICIDE RESIDUE IN A
C674497	USA	Granted	09/076,663	5/12/1998	6/13/2000	A2S	6,074,956	METHODS FOR PREVENTING SILICIDE RESIDUE
C675497	USA	Granted	09/118,382	7/17/1998	8/29/2000	A2S	6,110,779	METHOD AND STRUCTURE OF ETCHING A MEMORY
C675497	USA	Granted	09/617,820	7/17/2000	9/17/2002	A2S	6,452,225	METHOD AND STRUCTURE OF ETCHING A MEMORY
C677497	USA	Granted	09/092,924	6/8/1998	9/7/1999	A2S	5,948,703	METHOD OF SELF-LANDING GATE ETCHING TO
C679497	USA	Granted	09/548,616	4/13/2000	3/18/2003	A2S	6,534,411	METHOD OF HIGH DENSITY PLASMA METAL
C680497	USA	Granted	08/991,299	12/16/1997	6/6/2000	A2S	6,072,191	INTER-LEVEL DIELECTRIC CMP MONITOR
C680497	USA	Granted	09/548,741	4/13/2000	2/26/2002	A2S	6,350,627	INTERLEVEL DIELECTRIC THICKNESS MONITOR FOR
C686497	USA	Granted	09/002,783	1/5/1998	10/26/1999	A2S	5,972,749	METHOD AND APPARATUS FOR PREVENTING P1
C686497	USA	Granted	09/271,330	3/18/1999	5/23/2000	A2S	6,066,873	METHOD AND APPARATUS FOR PREVENTING P1
C687497	USA	Granted	08/991,052	12/16/1997	11/30/1999	A2S	5,994,780	SEMICONDUCTOR DEVICE WITH MULTIPLE
C687497	USA	Granted	09/353,781	7/15/1999	4/3/2001	A2S	6,211,058	SEMICONDUCTOR DEVICE WITH MULTIPLE
C690497	USA	Granted	09/531,749	3/20/2000	11/13/2001	A2S	6,316,293	METHOD OF FORMING A NAND-TYPE FLASH
C690497	USA	Granted	08/993,368	1/5/2000	12/23/2003	A2S	6,667,511	NOVEL NAND TYPE CORE CELL STRUCTURE FOR A
C692497	USA	Granted	08/982,186	12/17/1997	1/25/2000	A2S	6,017,786	METHOD FOR FORMING A LOW BARRIER HEIGHT
C694497	USA	Granted	09/000,739	12/30/1997	12/26/2000	A2S	6,166,439	A LOW DIELECTRIC CONSTANT MATERIAL AND
C695497	USA	Granted	09/352,801	7/13/1999	5/22/2001	A2S	6,235,586	THIN FLOATING GATE AND CONDUCTIVE SELECT
C696497	USA	Granted	08/986,860	12/8/1997	12/14/1999	A2S	6,001,688	POLY STRINGER CLEAN-UP FOR FLASH MEMORY
C700497	USA	Granted	08/986,951	12/8/1997	4/4/2000	A2S	6,046,085	ELIMINATION OF POLY STRINGER WITH STRAIGHT
C701497	USA	Granted	08/986,953	12/8/1997	8/3/1999	A2S	5,933,729	REDUCTION OF ONO FENCE DURING SELF-ALIGNED